



ZXTP01500BG

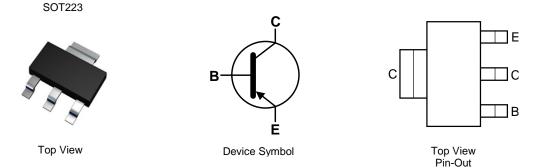
500V PNP HIGH PERFORMANCE TRANSISTOR IN SOT223

Features

- BV_{CEO} > -500V
- I_C = -150mA High Continuous Current
- I_{CM} = -500mA Peak Pulse Current
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- An Automotive-Compliant Part is Available Under Separate Datasheet (<u>ZXTP01500BGQ</u>)

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208(€3)
- Weight: 0.112 grams (Approximate)



Ordering Information (Note 4)

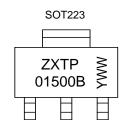
Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
ZXTP01500BGTC	Standard	ZXTP 01500B	13	12	4,000
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

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See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



ZXTP01500B = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 9 = 2019) WW or \overline{WW} = Week Code (01 to 53)



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-500	V
Collector-Emitter Voltage	V _{CEO}	-500	V
Emitter-Base Voltage	V _{EBO}	-7	V
Continuous Collector Current	Ic	-150	mA
Peak Pulse Current	I _{CM}	-500	mA

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	e Unit	
Power Dissipation	(Note 5)	Р	2	W
	(Note 6)	PD	3	W
Thermal Resistance, Junction to Ambient	(Note 5)	Р	62.5	°C/W
mermai Resistance, Junction to Ambient	(Note 6)	R _{θJA}	41.7	°C/W
Thermal Resistance, Junction to Leads (Note 7)		R _{0JL}	14.8	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C	

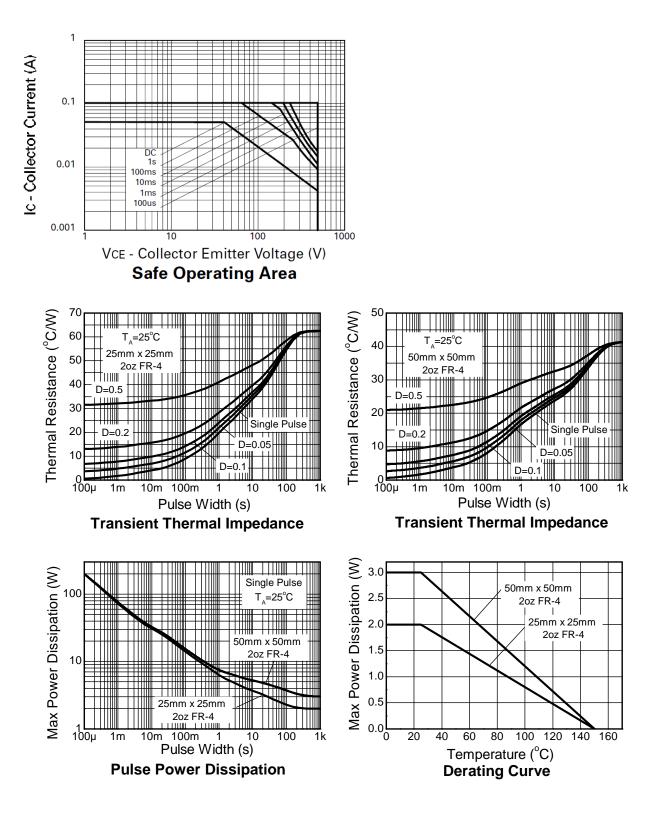
ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on 25mm × 25mm 2oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air So a device mounted with the collector lead on 25mm × 25mm × 25mm 202 copper that is conditions whilst operating in steady-state.
Same as note (5), except the device is mounted on 50mm × 50mm 202 copper.
Thermal resistance from junction to solder-point (at the end of the collector lead).
Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





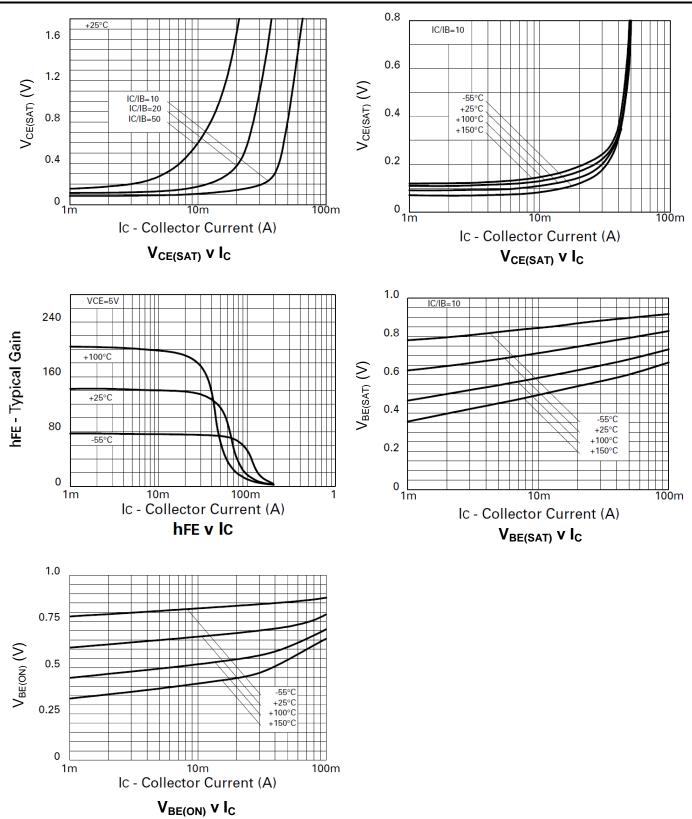
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-500	—	—	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 9)	BV _{CEO}	-500	—	—	V	$I_{\rm C} = -1 {\rm mA}$
Emitter-Base Breakdown Voltage	BVEBO	-7	—	—	V	I _E = -100μA
Collector Cut-Off Current	I _{CBO}	—	—	-100	nA	V _{CB} = -500V
Collector Cut-Off Current	I _{CES}	_	—	-100	nA	V _{CE} = -500V
Emitter Cut-Off Current	I _{EBO}	—	—	-100	nA	V _{EB} = -5.6V
Collector Emitter Seturation Voltage (Note 0)	V _{CE(SAT)}	—	_	-200	mV	$I_{\rm C} = -20 {\rm mA}, I_{\rm B} = -2 {\rm mA}$
Collector-Emitter Saturation Voltage (Note 9)		—	—	-500		$I_{C} = -50 \text{mA}, I_{B} = -10 \text{mA}$
Base-Emitter Saturation Voltage (Note 9)	V _{BE(SAT)}	_	—	-900	mV	$I_{C} = -50 \text{mA}, I_{B} = -10 \text{mA}$
Base-Emitter Turn-On Voltage (Note 9)	V _{BE(ON)}	—	_	-900	mV	$I_{C} = -50 \text{mA}, V_{CE} = -10 \text{V}$
		100	—	300		I _C = -1mA, V _{CE} = -10V
DC Current Gain (Note 9)	h _{FE}	80	—	300	—	$I_{C} = -50 \text{mA}, V_{CE} = -10 \text{V}$
		—	15	—		$I_{C} = -100 \text{mA}, V_{CE} = -10 \text{V}$
Current Gain-Bandwidth Product	f⊤	60	_	_	MHz	V _{CE} = -20V, I _C = -10mA f = 50MHz
Turn-On Time	t _{ON}	_	110	—	ns	V _{CC} = -100V, I _C = -50mA
Turn-Off Time	t _{OFF}	_	1.5	_	μs	I _{B1} = -5mA, I _{B2} = 10mA
Output Capacitance	C _{OBO}	_	—	8	pF	$V_{CB} = -20V, f = 1MHz$

Note: 9. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

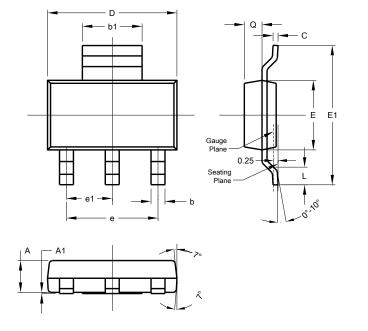




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

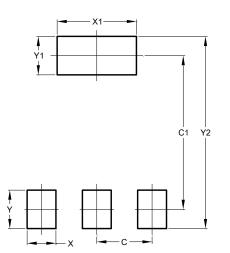
SOT223



	SOT223					
Dim	Min	Max	Тур			
Α	1.55	1.65	1.60			
A1	0.010	0.15	0.05			
b	0.60	0.80	0.70			
b1	2.90	3.10	3.00			
С	0.20	0.30	0.25			
D	6.45	6.55	6.50			
Е	3.45	3.55	3.50			
E1	6.90	7.10	7.00			
е	-	-	4.60			
e1	-	-	2.30			
L	0.85	1.05	0.95			
Q	0.84	0.94	0.89			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT223

Dimensions	Value (in mm)			
С	2.30			
C1	6.40			
Х	1.20			
X1	3.30			
Y	1.60			
Y1	1.60			
Y2	8.00			

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to creepage and clearance distances between device Terminals and PCB tracking.



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